

**Features**

- Low leakage current
- Low clamping voltage
- IEC 61000-4-2 (ESD Air): ±30kV
- IEC 61000-4-2 (ESD Contact): ±25kV
- IEC 61000-4-5 (Lightning 8/20μs): 4A

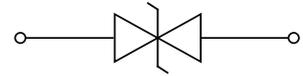
**Reverse Working Voltage**  
 5.0V Max.

**Low capacitance**  
 0.3pF(Typ.)

**DFN1006-2L**

**Applications**

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation, Digital Cameras
- Peripherals, Audio Players, Industrial Equipment

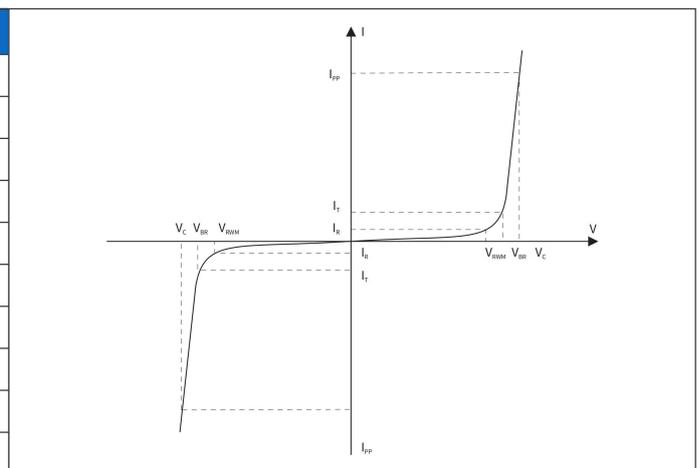


**Maximum Ratings ( Ta=25°C Unless otherwise specified)**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>ESD</sub>	Electrostatic Discharge Voltage	ESD per IEC 61000-4-2( Air )	±30	KV
		ESD per IEC 61000-4-2( Contact)	±25	KV
P <sub>PP</sub>	Peak Pulse Power	tp = 8/20 μs	60	W
I <sub>PP</sub>	Rated Peak Pulse Current	tp = 8/20 μs	4	A
T <sub>J</sub>	Operating JunctionTemperature Range	—	-55 to +150	°C
T <sub>STG</sub>	Operating JunctionTemperature Range	—	-55 to +150	°C

**Electrical Parameter**

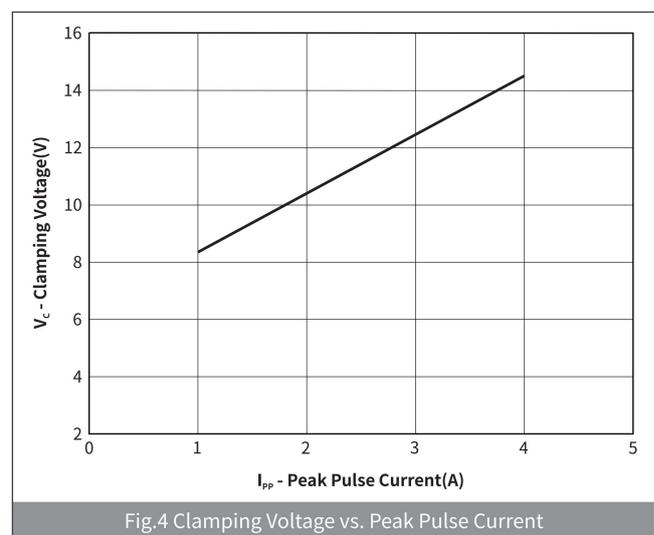
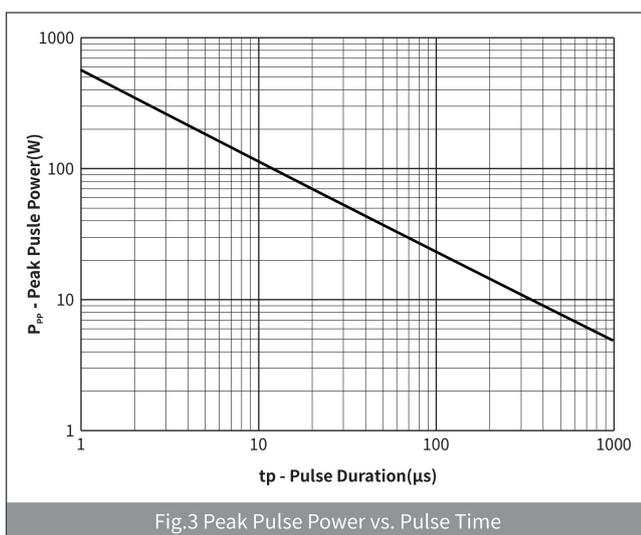
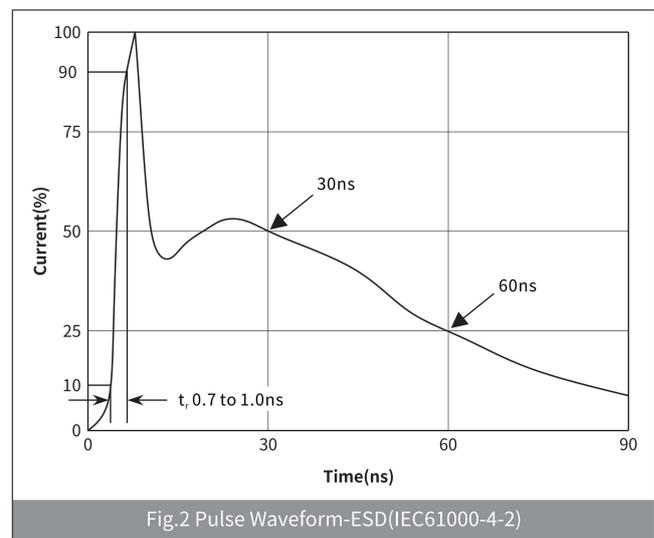
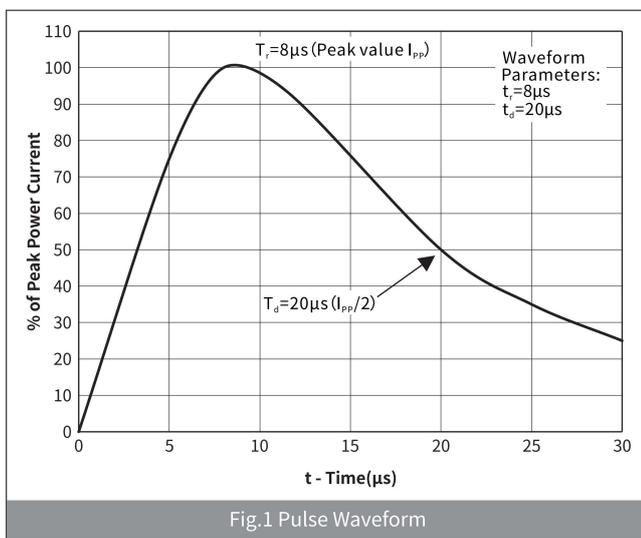
SYMBOL	PARAMETER
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>PP</sub>	Peak Pulse Current
I <sub>T</sub>	Test Current
I <sub>R</sub>	Reverse Leakage Current @ VRWM
V <sub>RWM</sub>	Peak Reverse Working Voltage
P <sub>PP</sub>	Peak Pulse Power Dissipation
C <sub>J</sub>	Junction Capacitance @ V <sub>R</sub> =0V,f=1MHz
I <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @I <sub>F</sub>



### Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	CONDITION	Min	Typ	Max	UNIT
Peak Reverse Working Voltage	$V_{RWM}$	$T_a=25^\circ\text{C}$	—	—	5.0	V
Breakdown Voltage	$V_{BR}$	$I_T=1.0\text{mA}, T_a=25^\circ\text{C}$	6.5	7.5	9.0	V
Reverse Leakage Current	$I_R$	$V_{RWM}=5.0\text{V}, T_a=25^\circ\text{C}$	—	—	0.08	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$	—	—	9	V
Clamping Voltage	$V_C$	$I_{PP}=4\text{A}, t_p=8/20\mu\text{s}$	—	—	15	V
Junction Capacitance	$C_J$	$V_{RWM}=0\text{V}, f=1\text{MHz}$	—	0.3	0.45	pF

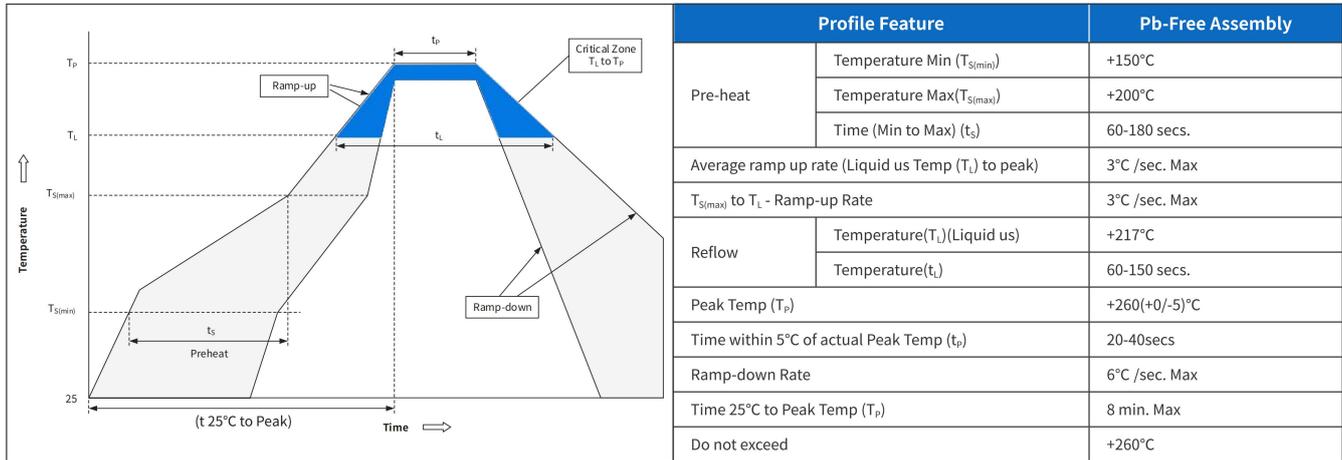
### Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



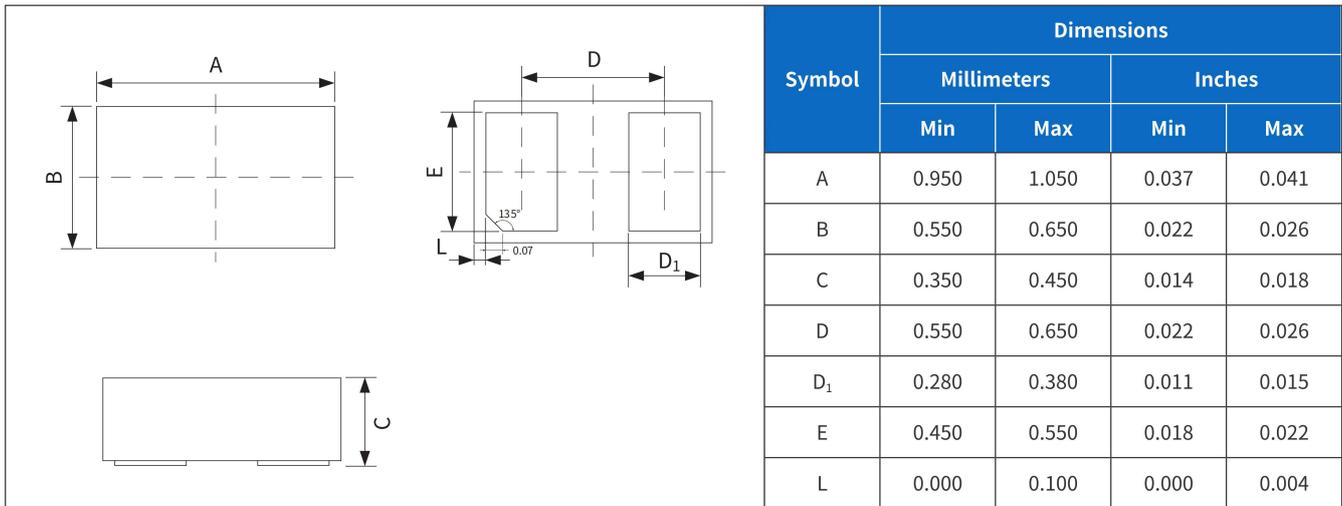
**Ordering Information**

PREFERRED P/N	PACKAGE	SIZE(mm)	DELIVERY MODE	MPQ(PCS)
H5VU10B	DFN1006	1.00×0.60×0.37	7" REEL	10,000

**Recommended Soldering Conditions**



**Package Outline Dimensions (DFN1006)**



**Suggested Pad Layout**

